

3.3V TO 18V MUX with Overcurrent Limit

Check for Samples: TPS22980

FEATURES

- Powered From 3.3V
- 4.5V to 19.8V High Voltage Switch
- 3V to 3.6V Switch
- Adjustable Current Limit
- Thermal Shutdown
- Make Before Break Switch
- High Voltage Discharge Before Low Voltage
 Make
- Reverse Current Blocking

DESCRIPTION

The TPS22980 is a current-limited power mux providing a connection to a peripheral device from either a low voltage supply (3.0V up to 3.6V) or a high voltage supply (5V up to 18V). The desired output is selected by digital control signals.

The high voltage (VHV) and low voltage (V3P3) switch current limits are set with external resistance. Once the current limit is reached, the TPS22980 will control the switch to maintain the current at the limit.

When the high voltage supply is not present, the TPS22980 will maintain the connection to the output from the low voltage supply. When a high voltage line and high voltage enable signal is detected by the device, the high voltage switch will be turned on in conjunction with the low voltage switch until a reverse current is detected by the low voltage switch. The low voltage switch is then disabled allowing a seamless transition from a low voltage to a high voltage supply with minimal drop and shoot-through current.

To prevent current backflow during a transition from a VHV connection to a V3P3 connection, the TPS22980 will break the VHV connection and discharge the output to approximately 3.3V. Once the output reaches 3.3V the device will connect V3P3 switch. If a load is present, the output will transition to 0V before returning to 3.3V.

The TPS22980 is available in a 4mm x 4mm x 1mm QFN package.

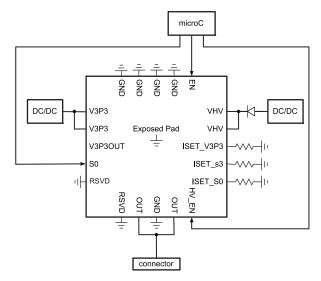


Figure 1. Typical Application

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

APPLICATIONS

- Notebook Computers
- Desktop Computers
- Power Management Systems

TPS22980

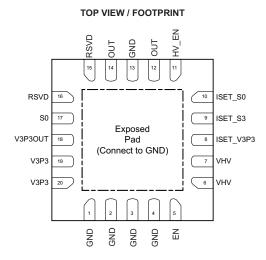
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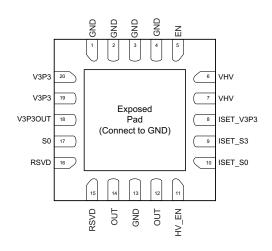


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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.





BOTTOM VIEW

Package Size: 4mm x 4mm x 1mm height, Pad Pitch: 0.5mm

	PIN	DESCRIPTION
NO.	NAME	DESCRIPTION
1		
2	GND	Device ground
3	GND	Device ground
4		
5	EN	Device Enable.
6	VHV	High voltage power supply input. Place a minimum of 0.1µF capacitor as close to this pin as possible.
7	VIIV	High voltage power supply input. Place a minimum of 0. The capacitor as close to this pin as possible.
8	ISET_V3P3	Sets the current limit for V3P3. Place resistor between this pin and GND. See Equation 1 to calculate resistor value.
9	ISET_S3	Sets the current limit for VHV in S3 mode. Place resistor between this pin and GND. See Equation 1 to calculate resistor value.
10	ISET_S0	Sets the current limit for VHV in S0 mode. Place resistor between this pin and GND. See Equation 1 to calculate resistor value.
11	HV_EN	High voltage output enable.
12, 14	OUT	Power output. Place a minimum of 1µF capacitor as close to this pin as possible.
13	GND	Device ground.
15	RSVD	Reserved, Must Tie to GND.
16	ROVD	Reserved. Must The to GND.
17	S0	When this pin is asserted, the device is put in S0 mode. Otherwise the device operates in S3 mode.
18	V3P3OUT	3.3V bypass output. Place a minimum of 0.1µF capacitor as close to this pin as possible.
19	V3P3	3.3V power supply input. Place a minimum of 0.1µF capacitor as close to this pin as possible.
20	voro	יישט אין
EP	GND	

PIN FUNCTIONS



ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)⁽¹⁾ ⁽²⁾

		VALUE	UNIT
	Input voltage range on V3P3 (VDD) ⁽³⁾	-0.3 to 3.6	
	Input voltage range on EN, HVEN, ISET_V3P3, ISET_S0, ISET_S3, S0 ⁽³⁾	-0.3 to V3P3+0.3	
VI	Input voltage range on VHV ⁽³⁾	-0.3 to 20	V
	Output voltage range at OUT ⁽³⁾	-0.3 to 20	
	Output voltage range at V3P3OUT ⁽³⁾	-0.3 to V3P3+0.3	
T _A	Operating ambient temperature range	-40 to 85	°C
T _{J (MAX)}	Maximum operating junction temperature	110	°C
T _{stg}	Storage temperature range	-65 to 150	°C
COD Dating	Charge Device Model (JESD 22 C101)	500	V
ESD Rating	Human Body Model (JESD 22 A114)	2	kV

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

In applications where high power dissipation and/or poor package thermal resistance is present, the maximum ambient temperature may (2)(2) In applications where high power dissipation and/or poor package inferior resistance is present, the maximum ambent temperature [T_{J(max)}], have to be de-rated. Maximum ambient temperature [T_{J(max)}] is dependent on the maximum operating junction temperature [T_{J(max)}], the maximum power dissipation of the device in the application [P_{D(max)}], and the junction-to-ambient thermal resistance of the part/package in the application (θ_{JA}), as given by the following equation: T_{A(max)} = T_{J(max)} - (θ_{JA} × P_{D(max)})
 (3) All voltage values are with respect to network ground terminal.

THERMAL INFORMATION

		TPS22980	
	THERMAL METRIC ⁽¹⁾	RGP	UNITS
		16 PINS 38.9 30.7 11.5	
θ_{JA}	Junction-to-ambient thermal resistance	38.9	
θ _{JCtop}	Junction-to-case (top) thermal resistance	30.7	
θ_{JB}	Junction-to-board thermal resistance	11.5	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	0.4	°C/VV
Ψ_{JB}	Junction-to-board characterization parameter	11.4	
θ _{JCbot}	Junction-to-case (bottom) thermal resistance	2.2	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

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TEXAS INSTRUMENTS

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RECOMMENDED OPERATING CONDITIONS

			MIN	MAX	UNIT
V _{3P3}		222	3.0	3.6	V
V _{HV}	Supply voltage range			19.8	V
I _{LIM3P3OUT}	V3P3OUT Switch	current range	0	500	mA
V _{IH}	Input logic high	EN, HV_EN, SO	V3P3-0.6	V3P3	V
V _{IL}	Input logic low	EN, HV_EN, S0	0	0.6	V
R _{SET_V3P3}	3.3V switch curre	3.3V switch current limit set resistance			
R _{SET_S0}	VHV switch curre	VHV switch current limit in S0 mode set resistance			
RS _{ET_S3}	VHV switch curre	nt limit in S3 mode set resistance	25.3	402	kΩ

ELECTRICAL CHARACTERISTICS

Unless otherwise noted the specification applies over the V_{DD} range and operating junction temp $-40^{\circ}C \le T_J \le 85^{\circ}C$. Typical values are for V_{3P3} = 3.3V, V_{HV} = 15V, and T_J = 25°C.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER SU	JPPLIES AND CURRENTS					
V _{3P3}	V3P3 Input voltage range		3	3.3	3.6	V
V _{HV}	VHV Input voltage range		4.5		19.8	V
I _{VHVACT}	Active quiescent current from VHV	HV_EN = 1, EN = 1			150	μA
I _{VHVSD}	Shutdown leakage current from VHV	HV_EN = 0, EN = 0 or 1			30	μA
IDDACT	Active quiescent current from V3P3	EN = 1, HV_EN = 0			200	μA
I _{DDACTHV}	Active quiescent current from V3P3	EN = 1, HV_EN = 1			150	μA
IDDSD	Shutdown Quiescent Current from V3P3	EN = 0, OUT = 0V			10	μA
I _{DIS}	OUT Discharge Current	$ EN = 1, V_{HV} = 5V \\ HV_EN = 1 \rightarrow 0 $	5		10	mA
		V = 0 V			1	μA
I _{IN}	HV_EN, EN, S0, S3 Input pin leakage	V = V3P3			1	μA
SWITCH A	ND RESISTANCE CHARACTERISTICS	•				
R _{SHV}	VHV Switch resistance	$V_{HV} = 5 V$ to 18V, $I_{VHV} = 1.5 A$			250	mΩ
R _{S3P3}	V3P3 Switch resistance	V _{3P3} = 3.3 V, I _{V3P3} = 1.5 A			250	mΩ
R _{S3P3BYP}	V3P3 Bypass switch resistance	V _{3P3} = 3.3 V, I _{V3P3} = 500 mA			500	mΩ
R _{OUTDIS}	OUT Pulldown resistance when disabled	EN = 0	1.5	2.5	4	kΩ
VOLTAGE	THESHOLDS	•				
、 <i>/</i>		VHV Input Falling	3.6	4		
V _{HVUVLO}	VHV Under voltage lockout	VHV Input Rising		4	4.3	V
、 <i>,</i>		V3P3 Input Falling	1.8	2.25		
V _{3P3UVLO}	V3P3 Under voltage lockout	V3P3 Input Rising		2.25	2.5	V
THERMAL	SHUTDOWN	•				
T _{SD}	Shutdown Temperature		110	120	130	°C
T _{SDHYST}	Shutdown Hysteresis			10		°C

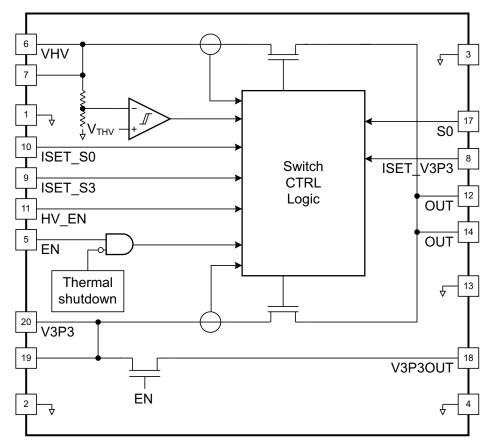


ELECTRICAL CHARACTERISTICS (continued)

Unless otherwise noted the specification applies over the V_{DD} range and operating junction temp $-40^{\circ}C \le T_J \le 85^{\circ}C$. Typical values are for V_{3P3} = 3.3V, V_{HV} = 15V, and T_J = 25°C.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
CURRENT	LIMIT					
		R _{SET_S0, 3} = 402 kΩ	100	110	150	
I_{LIMHV}	VHV Switch current limit state S0 or S3	R _{SET_S0, 3} = 80.6 kΩ	495	525	555	mA
		R _{SET_S0, 3} = 26.7 kΩ	1515	1575	1635	
		R_{SET_V3P3} = 402 k Ω	100	110	150	
I _{LIM3P3}	V3P3 Switch current limit	R _{SET_V3P3} = 80.6 kΩ	495	525	555	mA
		R _{SET_V3P3} = 26.7 kΩ	1515	1575	1635	
I _{REV3P3}	V3P3 Switch Reverse Current Limit		10	27	45	mA
T _{V3P3RC}	V3P3 Switch Reverse Current Response Time	$V_{OUT} = V_{3P3} \rightarrow V_{3P3} + 20mV$			100	μS
T _{VHVSC}	VHV Switch short circuit response time	C _{OUT} = 20 pF		8		μs
T _{V3P3SC}	V3P3 Switch short circuit response time	C _{OUT} = 20 pF		8		μs
TRANSITI	ON DELAYS					
T _{3P3OFF}	VHV to V3P3 off time	$C_{OUT} = 1.1 \mu F$, EN = 1, HV_EN = 1 \rightarrow 0			6	ms
T _{0-3.3V}	0V to 3.3V ramp time	C _{OUT} ≤ 20 pF			6	ms
T _{3.3V-VHV}	3.3V to VHV ramp time	C _{OUT} ≤ 20 pF			6	ms
T _{VHV-3.3V}	VHV to 3.3V ramp time	C _{OUT} ≤ 20 pF			23	ms
T _{LIM}	Overcurrent response time	C _{OUT} ≤ 20 pF			0.5	ms

FUNCTIONAL BLOCK DIAGRAM



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APPLICATION INFORMATION

CURRENT LIMIT

The TPS22980 provides current limiting in the power switches. Both the VHV supply current limit and the V3P3 supply current limit are adjustable by external resistors.

Figure 2 shows a simplified view of the TPS22980 current limit function. Both the VHV supply current limit and the V3P3 supply current limit are adjustable by external resistors.



CURRENT LIMIT THRESHOLD

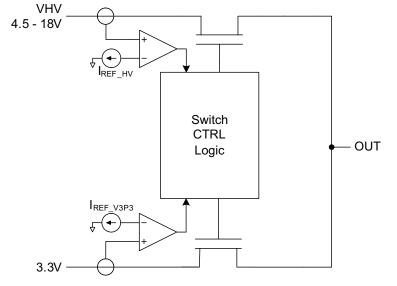


Figure 2. Simplified Current Limit Diagram

The current limit thresholds, I_{REF_HV} and I_{REF_V3P3} , are set with three external resistors as shown in Figure 3. When the TPS22980 is passes the V3P3 voltage, the current limit is set by R_{ISET_V3P3} . The VHV path has two modes that support two different current limits which are selected by the S0 pin. When S0 is asserted high, $R_{ISET_{S0}}$ sets the current limit. When S0 is low, $R_{ISET_{S3}}$ sets the current limit. This allows the system to have two separate VHV current limits for different modes such as active and sleep.

ISET V3P3

ISET_S3

RSET V3P3

RSET S3

RSET SO



ISET_S0



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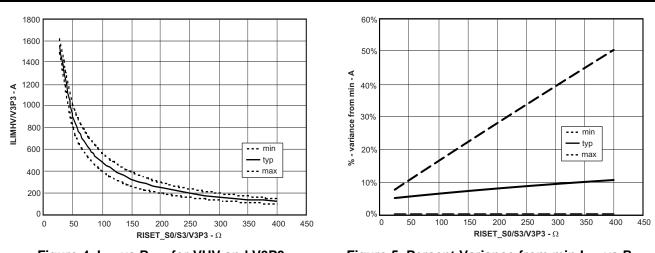


Figure 4. I_{LIM} vs R_{SET} for VHV and V3P3



Figure 4 shows the minimum, typical, and maximum current limit for either supply versus its corresponding RISET value. Equation 1 is used to determine the RISET needed to set a minimum ILIM for a given supply and mode. Figure 5 shows the approximate variation from the set minimum I_{LM} value to the typical and maximum I_{LM} values.

$$RISET = \frac{40 \text{ k}\Omega \times \text{Amps}}{\text{IL IMmin}}$$

ILIMmin

(1)

where:

R_{ISET} = external resistor used to set the current limit for V3P3, VHV (S0), or VHV (S3), and

ILIMmin = current limit for V3P3, VHV (S0), or VHV (S3) set by the external RISET resistor.

Each resistor is placed between the corresponding ISET pin and GND, as shown in Figure 3, providing a minimum current limit between 100mA and 1.5A.

TRANSITION DELAYS

Output transitions of the TPS22980 voltages are shown in Figure 6. When the device transitions from VHV to V3P3 at the output, the power switches both turn off until the output falls to near the V3P3 voltage. During this time, a discharge current (IDIS) pulls OUT down. If a load on the line is also pulling OUT down, the output can drop to 0V due to the switch off time of T3P3OFF. Figure 7 shows the voltage drop on the output during this transition with no output capacitance.



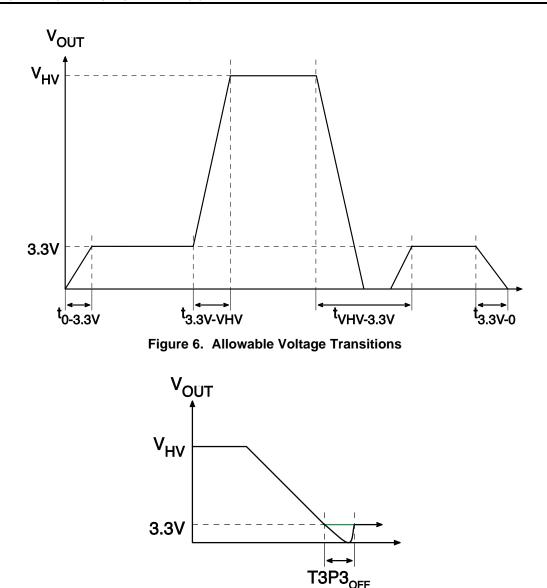


Figure 7. Voltage Drop During Transitions from VHV

DIGITAL CONTROL SIGNALS

The voltage at OUT is controlled by two digital logic input signals, EN and HV_EN. HV_EN controls the state of the VHV switch and EN controls the state of V3P3 switch. Table 1 lists the possible output states given the conditions of the digital logic signals. State PD indicates a pulldown resistance of R_{OUTDIS} to GND.

EN	HV_EN	OUT
0	0	PD
0	1	PD
1	0	V3P3
1	1	VHV

Table 1. Output State of OUT Given the States EN and HV_EN



Figure 8 shows possible combinations of EN and HV_EN controlling OUT of the TPS22980.

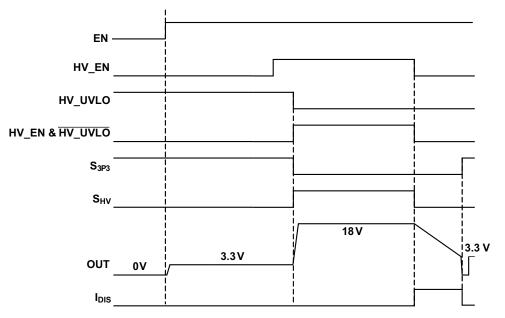


Figure 8. Logic Waveforms Displaying the Transition Between VHV and V3P3

OVER-CURRENT LIMIT AND SHORT CIRCUIT PROTECTION

When the load at OUT attempts to draw more current than the limit set by the external RISET resistors for the V3P3 switch and VHV switch (for both S0 and S3 modes), the device will operate in a constant current mode while lowering the output voltage. Figure 9 shows the delay, t_{LIM} , which occurs when an over-current fault is detected until the output current is lowered to ILIMHV tolerances for VHV or ILIM3V3 tolerances for V3P3 as shown in Figure 4.

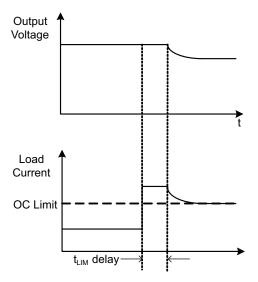


Figure 9. Overcurrent Output Response

All short circuit conditions are treated as over-current conditions. In the event of a short circuit, the device will limit the output current to the corresponding R_{SET} value and continue to do so until thermal shutdown is encountered or the short circuit condition is removed.

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Reverse Current Protection

Reverse current protection for the V3P3 supply to OUT triggers at I_{REV3P3} causing the V3P3 supply switch to open. When the HV_EN signal is not asserted and reverse current protection is triggered, a discharge current source is turned on to bring the output voltage to 3.3V nominal.

Thermal Shutdown

The device enters thermal shutdown when junction temperature reaches T_{SD} . The device will resume the previous state on power up once the junction temperature has dropped by 10°C. Connect thermal vias to the exposed GND pad underneath the device package for improved thermal diffusion.

UVLO

When the VHV rail reaches the under-voltage lockout threshold of V_{HVUVLO} while HV_EN is high, the device will switch back to V3P3. Once the UVLO condition has cleared, the device will switch to VHV again. When the V3P3 rail reaches the under-voltage lockout threshold of $V_{3P3UVLO}$, regardless of the states of any digital logic controls, the device will open all switches and enter a reset condition.

Input Inductive Bounce at Short Circuit

When the TPS22980 is operating at high currents and high input voltage on VHV, a short circuit condition can cause the input to exceed the maximum safe operating condition for VHV. When a significant inductance is present at the VHV input, sudden turn off of current through the device may produce a large enough inductive voltage bounce that exceeds the maximum safe operating condition and may damage the TPS22980. To prevent this, reduce any inductance at the input. Input capacitors, such as 4.7μ F, can reduce the supply bounce and are recommended.

Single Point Failure Protection

The TPS22980 current limits are set by the RISET resistances. Shorting one of these resistance would result in a single point failure that removes the current limiter for that particular input and mode. Without current limiting, an excessive current load may damage the TPS22980 and the system. To prevent a single point failure from occurring, the RISET resistances can be divided into two series resistances each as shown in Figure 10. Failure of a single resistance will not result in runaway current and damage.

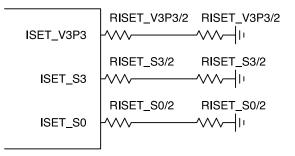


Figure 10. R_{ISET} Division to Prevent Single Point Failure



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REVISION HISTORY

Changes from Original (December 2011) to Revision A	Page
Changed Typical Application figure.	
Added bottom view pin out information.	
Updated Pin Functions Table.	
Added reverse current and thermal shutdown parameters to the ELECTRICAL CHARACTE	ERISTICS table 4
Updated the APPLICATION INFORMATION section.	
 Changes from Revision A (February 2012) to Revision B Changed bottom view pin out information. 	Page
Changes from Revision B (April 2012) to Revision C	Page
Removed ordering information table.	2
Added R _{OUTDIS} parameter to the Electrical Characteristics table.	
Updated the DIGITAL CONTROL SIGNALS section.	



25-Sep-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)		(3)		(4/5)	
TPS22980RGPR	ACTIVE	QFN	RGP	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	PS22980	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal	

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS22980RGPR	QFN	RGP	20	3000	330.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

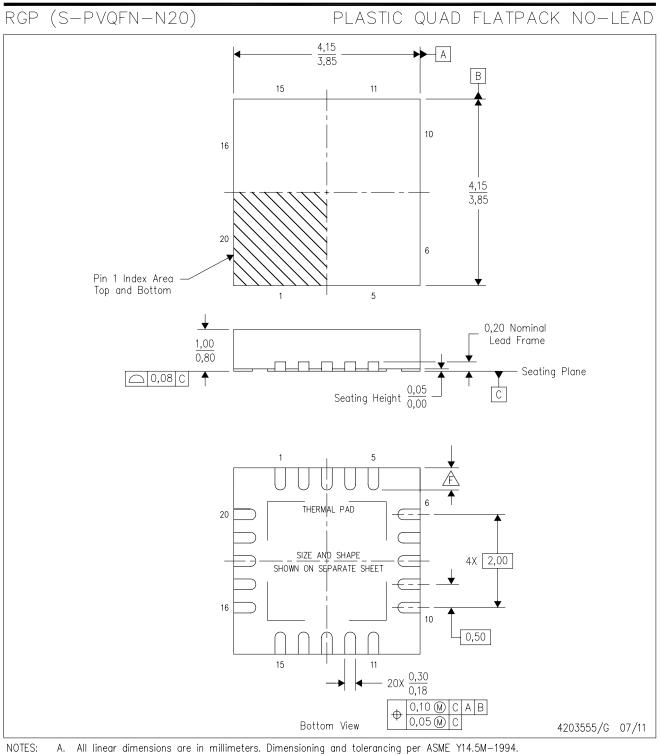
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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS22980RGPR	QFN	RGP	20	3000	367.0	367.0	35.0

MECHANICAL DATA



All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. Α.

- Β. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.

D. The package thermal pad must be soldered to the board for thermal and mechanical performance.

- See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions. E.
- 🖄 Check thermal pad mechanical drawing in the product datasheet for nominal lead length dimensions.



RGP (S-PVQFN-N20)

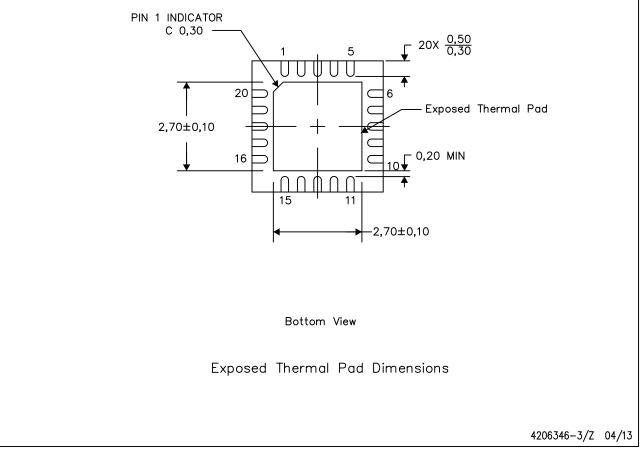
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

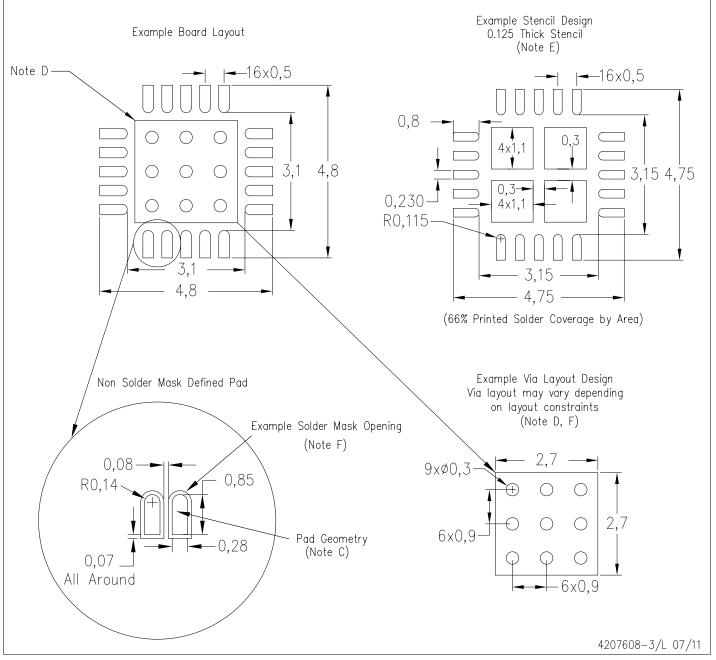


NOTES: A. All linear dimensions are in millimeters



RGP (S-PVQFN-N20)

PLASTIC QUAD FLATPACK NO-LEAD



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>.
 - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
 - F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.

NSTRUMENTS www.ti.com

EXAS

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